

Spezifikationen	
Artikelnummer	PSMN3R0-60PS,127
Hersteller	Nexperia
Beschreibung	MOSFET N-CH 60V 100A TO220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2666 pcs Stock
VGS (th) (Max) @ Id	4V @ 1mA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	TO-220AB
Serie	-
Rds On (Max) @ Id, Vgs	3 mOhm @ 25A, 10V
Verlustleistung (max)	306W (Tc)
Verpackung	Tube
Verpackung / Gehäuse	TO-220-3
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Eingabekapazität (Ciss) (Max) @ Vds	8079pF @ 30V
Gate Charge (Qg) (Max) @ Vgs	130nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	10V
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	100A (Tc)

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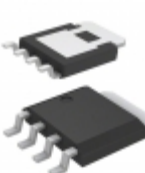
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PSMN3R060PS NXP



PSMN3R0-60ES,127
 Nexperia USA Inc.
 MOSFET N-CH 60V 100A I2PAK



PSMN3R2-25YLC,115
 NXP USA Inc.
 MOSFET N-CH 25V 100A LFPACK



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PSMN3R0-60PS MOS
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Mehr

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